# 67C401/13, 67C402/23

Low Density First-In First-Out (FIFO) 64 x 4, 64 x 5 CMOS Memory (Cascadable)



# **DISTINCTIVE CHARACTERISTICS**

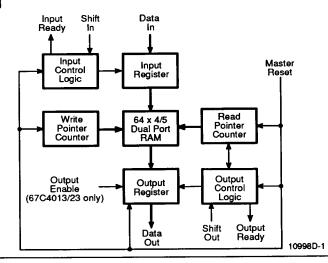
- Zero standby power
- High-speed 15 MHz shift-in/shift-out rates
- Very low active power consumption
- TTL-compatible inputs and outputs
- Readily expandable in word width and depth
- RAM-based architecture for short fall-through delay
- Full CMOS cell for maximum noise immunity
- Asynchronous operation
- Output enable feature (67C4013/23)

## **GENERAL DESCRIPTION**

The 67C40X/XX series devices are high-performance CMOS RAM-based First-In First-Out (FIFO) buffer memory products organized as 64 words by 4 or by 5, bits wide. These devices use Advanced Micro Devices latest CMOS process technology and meet the demands for high-speed, low-power operation. By utilizing an on-chip, dual-port RAM, a very short fall-through time is realized, thus improving overall system performance. By using both Read and Write pointers for addressing

each memory location, the data can propagate to the outputs in much less time than in traditional register-based FIFOs. These FIFOs are easily integrated into many applications and perform particularly well for high-speed disc controllers, graphics, and communication network systems. The  $550\,\mu\text{W}$  standby power specification makes these devices ideal for ultra-low power and battery-powered systems.

### **BLOCK DIAGRAM**

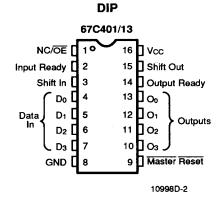


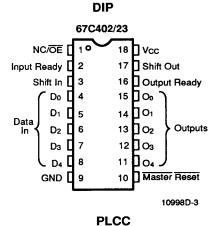
# PRODUCT SELECTOR GUIDE

Part Number	67C401-10 67C4013-10 67C402-10 67C4023-10	67C401-15 67C4013-15 67C402-15 67C4023-15
Shift-In/Shift-Out Rate Operating Frequency	10 MHz	15 MHz
Maximum Power Supply Current	35 mA	45 mA
Operating Range	Com'l	Com'l

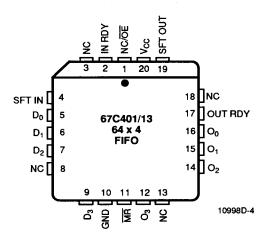
Publication# 10998 Rev. D Amendment/0 Issue Date: September 1992

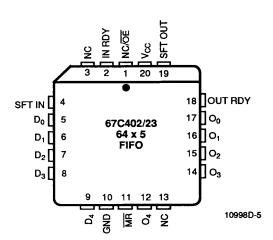
## **CONNECTION DIAGRAMS**





**PLCC** 

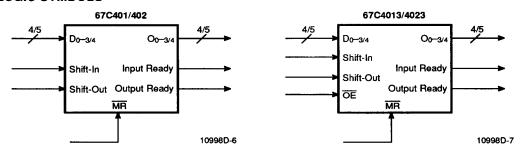




### Note:

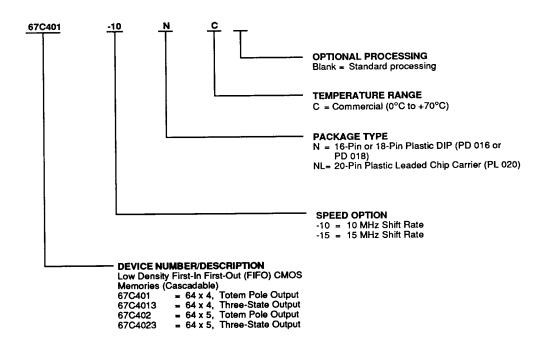
1. Pin 1 is marked for orientation for plastic packages.

## **LOGIC SYMBOLS**



# ORDERING INFORMATION Standard Products

AMD standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of:



Valid Combinations				
67C401-10				
67C401-15				
67C4013-10				
67C4013-15	]			
67C402-10	N, NL			
67C402-15				
67C4023-10				
67C4023-15				

### Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.



### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage Vcc	0.5 V to	+7.0 V
Input Voltage	−1.5 V to	+7.0 V
Off-state Output Voltage	-0.5 to Vcc	+0.5 V
Storage Temperature	-65°C to -	+150°C
Power Dissipation		10W

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. This is a stress rating only; functional operation of the device at these limits or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure of the device to absolute maximum ratings for extended periods may affect device reliability.

# **OPERATING RANGES**

Commercial (C) Devices

Ambient Temperature (T<sub>A</sub>)
Operating in Free Air ...... 0°C to +70°C
Supply Voltage (Vcc)

with Respect to Ground ..... +4.50 V to +5.50 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

# **OPERATING CONDITIONS, Commercial**

Parameter			-10		-15		
Symbol	Parameter Description	Figure	Min.	Max.	Min.	Max.	Unit
fin	Shift in rate	1		10		15	MHz
tsin*	Shift in HIGH time	1	16		16		ns
tsı.*	Shift in LOW time	1	30		30		ns
tios	Input data setup to SI (Shift In)	1	0		0		ns
tiDH	Input data hold time from SI (Shift In)	1	40		40		ns
triDs	Input data setup to IR (Input Ready)	3	0		0		ns
trion	Input data hold time from IR (Input Ready)	3	30		30		ns
four	Shift out rate	4		10		15	MHz
tson*	Shift out HIGH time	4	24		21		ns
tsoL*	Shift out LOW time	4	30		30		ns
tmrw	Master Reset pulse	8	35		35		ns
tmrs	Master Reset to SI	8	65		65		ns

<sup>\*</sup>See AC test and high-speed application note.



# DC CHARACTERISTICS over COMMERCIAL operating range unless otherwise specified

			-10		-15			
Parameter Symbol	Parameter Description	Test Condition		Min.	Max.	Min.	Max.	Unit
VIL*	Low-level input voltage			0.8		0.8		V
ViH*	High-level input voltage			2		2		V
lin	Input Current	Vcc = Max.,	GND <vin <vcc<="" td=""><td>-1</td><td>1</td><td>-1</td><td>1</td><td>μА</td></vin>	-1	1	-1	1	μА
loz	Off-state output current	Vcc = Max., GND <vout <vcc<="" td=""><td>-5</td><td>5</td><td><b>-</b>5</td><td>5</td><td>μА</td></vout>		-5	5	<b>-</b> 5	5	μА
			loL = 20 μA		0.1		0.1	J
Vol	Low-level output voltage	Vcc = Min.	loL = 8 mA		0.4		0.4	] <u> </u>
	High-level output voltage	Vcc = Min.	Юн = −20 μА	Vcc - 0.1		Vcc - 0.1		V
Vон			юн = -4 mA	2.4		2.4		
los**	Output short-circuit current	Vcc = Max.	Vo = 0 V	-90	-20	-90	-20	mA
	Standby supply current		VIH = VCC VIL = GND		100		100	μА
lcc	Operating supply current	Vcc = Max. lout = 0	VIH = Min., VIL = Max. fin = fout = Max.		35		45	mA

VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with
respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values
without suitable equipment.

# SWITCHING CHARACTERISTICS over COMMERCIAL operating range unless otherwise specified

Parameter		-10		-15			
Symbol	Parameter Description	Figure	Min.	Мах.	Min.	Max.	Unit
tirL*	Shift in ↑ to Input Ready Low	1		60_	l	55	ns
tinn•	Shift in ↓ to Input Ready HIGH			55		55	ns
torL*	Shift Out ↑ to Output Ready LOW			55		47	ns
torn*	Shift Out ↓ to Output Ready HIGH			50		47	ns
toph	Output Data Hold (previous word)	4	5		5		ns
tops	Output Data Shift (next word)			35		33	ns
tрт	Data throughput	3,6		100		90	ns
<b>tm</b> RORL	Master Reset ↓ to Output Ready LOW			100		100	ns
tmairh	Master Reset ↓ to Input Ready HIGH	8		100		100	ns
tmro	Master Reset ↓ to Outputs LOW			35		35	ns
tiph	Input Ready pulse HIGH	3	19		16		ns
topн	Output Ready pulse HIGH	6	16		16		ns
tord	Output Ready ↑ to Data Valid	4		-3		-3	ns
t <sub>PHZ</sub> ···				25		25	ns
tpLz**	Output Disable Delay	١.		25	1	25	] '''
tpzL**		Α .		30		30	ns
tpzH**	Output Enable Delay			30		30	]

<sup>\*</sup>See AC test and high-speed application note.

<sup>\*\*</sup>Enable/Disable delays refer to 67C4013/23 only.

# **CAPACITANCES\***

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Cin	Input capacitance	T <sub>A</sub> = 25°C, f = 1 MHz		10	
Cour	Output capacitance	Vcc = 4.5 V		7	pF

<sup>\*</sup> These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

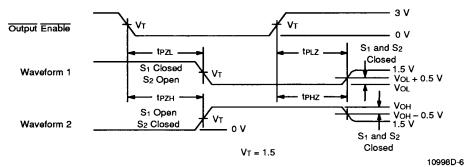
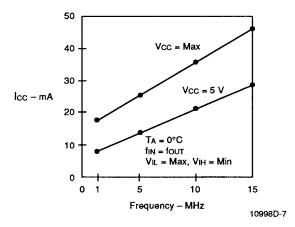


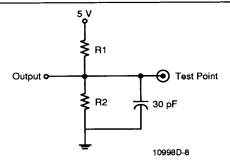
Figure A. Enable and Disable

### Notes:

- Waveform 1 is for a data output with internal conditions such that the output is low except when disabled by the output control.
- Waveform 2 is for a data output with internal conditions such that the output is high except when disabled by the output control.

## Icc vs. Frequency



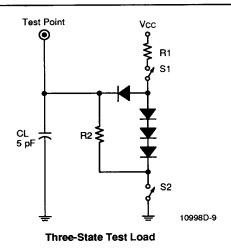


### **Resistor Values**

loL	R1	R2	
8 mA	600 Ω	1200 Ω	

## Standard AC Test Load

Input Pulse Ampitude = 3 V Input Rise and Fall Time (10% – 90%) = 2.5 ns Measurements made at 1.5 V All Diodes are 1N916 or 1N3064



# FUNCTIONAL DESCRIPTION Data Input

The FIFO consists of a dual-port RAM and two ring counters for read and write. After power-up, the Master Reset should be pulsed LOW, which internally rests both the read and write counters. When the Ready (IR) is HIGH, the FIFO is ready to accept DATA from the Dx inputs. Data then present at the inputs is written into the first location of the RAM when Shift-In (SI) is brought HIGH. A SI HIGH signal causes the IR to go LOW. When the SI is brought LOW and the FIFO is not full, IR will go HIGH, indicating that more room is available. The write pointer now points to the next location in the RAM. If the memory is full, then the IR will remain LOW.

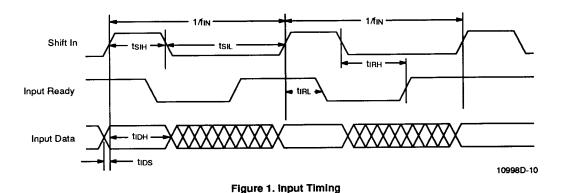
### **Data Output**

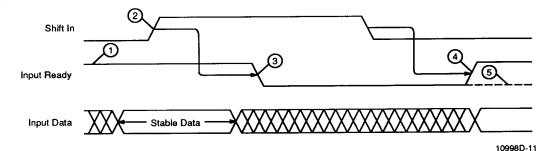
Data is read from Ox outputs. Just after the first shift-in, the first data word is available at the outputs, which is indicated by the Output Ready (OR) going HIGH. When the OR is HIGH, data may be shifted out by bringing the Shift-Out (SO) HIGH. A HIGH signal at SO causes the read pointer to point to the next location in the RAM, and also the OR to go LOW. Valid data is maintained while the SO is HIGH. When the SO is brought LOW, the OR goes HIGH, indicating the presence of new valid data. If the FIFO is emptied, OR stays LOW, and Ox remains as before, (i.e., data does not change if the FIFO is empty). A dual-port RAM inside the chip provides the capability of simultaneous and asynchronous write (Shift-Ins) and reads (Shift-Outs).

# **AC TEST AND HIGH-SPEED APPLICATION NOTES**

Since the FIFO is a very-high-speed device, care must be exercised in the design of the hardware and the timing utilized within the design. Device grounding decoupling is crucial to correct operation as the FIFO will respond to very small glitches due to long reflective lines, high capacitances and/or poor supply decoupling and grounding. Advanced Micro Devices recommends a monolithic ceramic capacitor of 0.1 µF directly between Vcc and GND with very short lead length. In addition, care must be exercised in how the timing is set and how the parameters are measured. For example, since an AND gate function is associated with both the Shift-In-Input Ready combination, as well as the Shift-Out-Output Ready combination, timing measurements may be misleading; i.e., a rising edge of the Shift-In pulse is

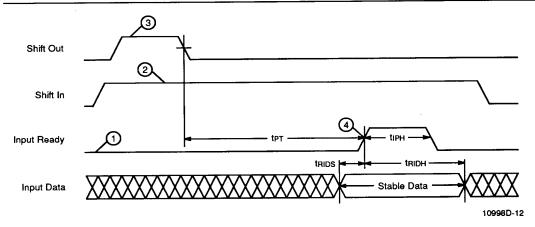
not recognized until Input Ready is HIGH. If Input Ready is not HIGH due to (a) too high a frequency, or (b) FIFO being full or affected by Master Reset, the Shift-In activity will be ignored. This will affect the device from a functional standpoint, and will also cause the "effective" timing of Input Data Hold time (tiph) and the next activity of Input Ready (tirl.) to be extended relative to Shift-In going HIGH. The same type of problem also relates to tirl, torl, and torl. For high-speed applications, proper grounding technique is essential. In order to diminish timing ambiguittes between the Shift-In-Input-Ready or Shift-Out-Output-Ready pairs when operating at high frequencies, it is recommended that the tsih and tsoh pulse widths be as short as possible within the specified limits.





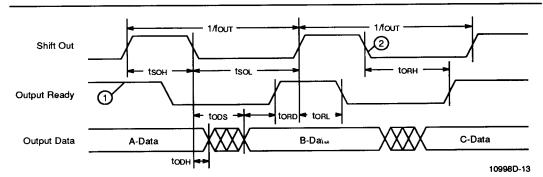
- Input Ready HIGH indicates space is available and a Shift-In pulse may be applied.
- 2. Input Data is loaded into the first available memory location.
- 3. Input Ready goes LOW indicating this memory location is full.
- Shift-In going LOW allows Input Ready to sense the status of the next memory location. The next memory location is empty as indicated by Input Ready HIGH.
- If the FIFO is already full, then the Input Ready remains LOW.Note: Shift-In pulses applied while Input Ready is LOW will be ignored.

Figure 2. The Mechanism of Shifting Data into the FIFO



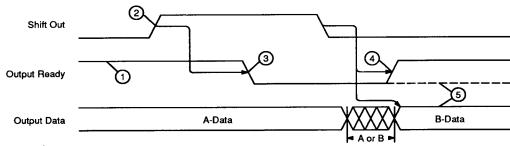
- 1. FIFO is initially full.
- 2. Shift-In is held HIGH.
- 3. Shift-Out pulse is applied. An empty location is detected by the internal pointers on the falling edge of SO.
- 4. As soon as Input Ready becomes HIGH, the Input Data is loaded into this location.

Figure 3. Data is shifted in whenever Shift-In and input Ready are Both HIGH



- The diagram assumes that the FIFO contains at least three words: A-Data (first input word), B-Data (second input word), and C-Data (third input word).
- 2. Output data changes on the falling edge of SO after a valid Shift-Out Sequence, i.e., OR and SO are both high together.

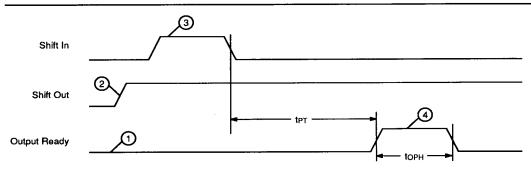
Figure 4. Output Timing



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- 1. Output Ready HIGH indicates that data is available and a Shift-Out pulse may be applied.
- Shift-Out goes HIGH causing B-Data (second input word) to advance to the output register. Output data remains as valid A-Data while Shift-Out is HIGH.
- 3. Output Ready goes LOW.
- 4. Shift-Out goes LOW causing Output Ready to go HIGH and new data (B) to appear at the data outputs.
- 5. If the FIFO has only one word loaded (A-Data) then Output Ready stays LOW and the output data remains the same (A-Data).

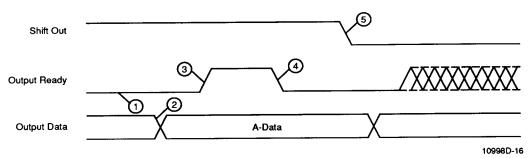
Figure 5. The Mechanism of Shifting Data Out of the FIFO



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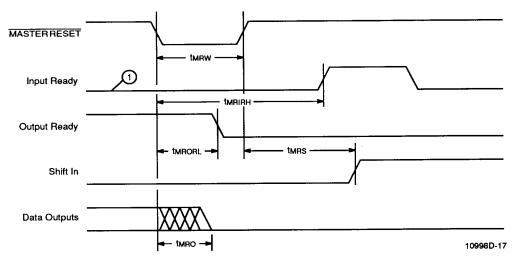
- 1. FIFO initially empty.
- 2. Shift-Out held HIGH.
- 3. Shift-In pulse applied. A full location is detected by the internal pointers on the falling edge of Shift-In.
- 4. As soon as Output Ready becomes HIGH, the word is shifted out.

Figure 6. tpt and toph Specification



- 1. The internal logic does not detect the presence of any words in the FIFO.
- 2. New data (A) arrives at the outputs.
- 3. Output Ready goes HIGH indicating arrival of the new data.
- 4. Since Shift-Out is held HIGH, Output Ready goes immediately LOW.
- As soon as Shift-Out goes LOW, the Output Data is subject to change. Output Ready will go HIGH or remain LOW depending on whether there are any additional words in the FIFO.

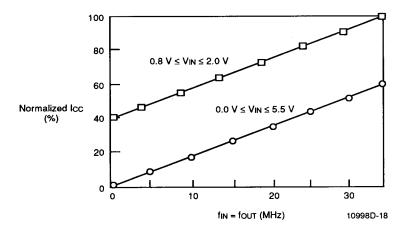
Figure 7. Data is Shifted Out Whenever Shift Out and Output Ready are Both HIGH



1, FIFO is initially full.

Figure 8. Master Reset Timing

# NORMALIZED Icc vs FREQUENCY



 $T_A = 0$ °C,  $V_{CC} = 5.5 \text{ V}$ ,  $f_{IN} = f_{OUT}$